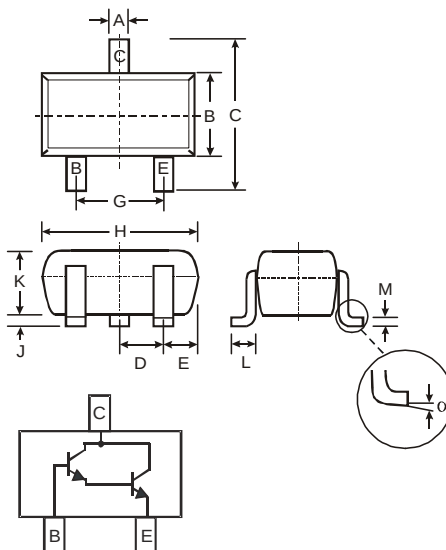


## Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- High Current Gain
- Ultra-Small Surface Mount Package
- **Lead Free/RoHS Compliant (Note 2)**
- **"Green" Device (Note 3 and 4)**

## Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: K1D - See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



| SOT-323              |              |      |
|----------------------|--------------|------|
| Dim                  | Min          | Max  |
| A                    | 0.25         | 0.40 |
| B                    | 1.15         | 1.35 |
| C                    | 2.00         | 2.20 |
| D                    | 0.65 Nominal |      |
| E                    | 0.30         | 0.40 |
| G                    | 1.20         | 1.40 |
| H                    | 1.80         | 2.20 |
| J                    | 0.0          | 0.10 |
| K                    | 0.90         | 1.00 |
| L                    | 0.25         | 0.40 |
| M                    | 0.10         | 0.18 |
| $\alpha$             | 0°           | 8°   |
| All Dimensions in mm |              |      |

## Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                                   | Symbol                            | Value       | Unit |
|--------------------------------------------------|-----------------------------------|-------------|------|
| Collector-Base Voltage                           | V <sub>CB0</sub>                  | 40          | V    |
| Collector-Emitter Voltage                        | V <sub>CE0</sub>                  | 40          | V    |
| Emitter-Base Voltage                             | V <sub>EB0</sub>                  | 12          | V    |
| Collector Current - Continuous (Note 1)          | I <sub>C</sub>                    | 500         | mA   |
| Power Dissipation (Note 1)                       | P <sub>d</sub>                    | 200         | mW   |
| Thermal Resistance, Junction to Ambient (Note 1) | R <sub>θJA</sub>                  | 625         | °C/W |
| Operating and Storage Temperature Range          | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                       | Symbol               | Min                        | Max                           | Unit | Test Condition                                                                                                                                    |
|--------------------------------------|----------------------|----------------------------|-------------------------------|------|---------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>OFF CHARACTERISTICS (Note 5)</b>  |                      |                            |                               |      |                                                                                                                                                   |
| Collector-Base Breakdown Voltage     | V <sub>(BR)CBO</sub> | 40                         | —                             | V    | I <sub>C</sub> = 100μA, I <sub>E</sub> = 0                                                                                                        |
| Collector-Emitter Breakdown Voltage  | V <sub>(BR)CEO</sub> | 40                         | —                             | V    | I <sub>C</sub> = 100mA, I <sub>B</sub> = 0                                                                                                        |
| Emitter-Base Breakdown Voltage       | V <sub>(BR)EBO</sub> | 12                         | —                             | V    | I <sub>E</sub> = 10μA, I <sub>C</sub> = 0                                                                                                         |
| Collector Cutoff Current             | I <sub>CBO</sub>     | —                          | 50                            | nA   | V <sub>CB</sub> = 30V, I <sub>E</sub> = 0                                                                                                         |
| Collector Cutoff Current             | I <sub>CEO</sub>     | —                          | 1.0                           | μA   | V <sub>CE</sub> = 25V, I <sub>B</sub> = 0                                                                                                         |
| Emitter Cutoff Current               | I <sub>EBO</sub>     | —                          | 50                            | nA   | V <sub>EB</sub> = 10V, I <sub>C</sub> = 0                                                                                                         |
| <b>ON CHARACTERISTICS (Note 5)</b>   |                      |                            |                               |      |                                                                                                                                                   |
| DC Current Gain                      | h <sub>FE</sub>      | 10,000<br>20,000<br>14,000 | 100,000<br>200,000<br>140,000 | —    | I <sub>C</sub> = 10mA, V <sub>CE</sub> = 5.0V<br>I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5.0V<br>I <sub>C</sub> = 500mA, V <sub>CE</sub> = 5.0V |
| Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub> | —                          | 1.2<br>1.5                    | V    | I <sub>C</sub> = 50mA, I <sub>B</sub> = 0.5mA<br>I <sub>C</sub> = 500mA, I <sub>B</sub> = 0.5mA                                                   |
| Base-Emitter Saturation Voltage      | V <sub>BE(SAT)</sub> | —                          | 2.0                           | V    | I <sub>C</sub> = 500mA, I <sub>B</sub> = 0.5mA                                                                                                    |
| Base-Emitter On Voltage              | V <sub>BE(ON)</sub>  | —                          | 1.75                          | V    | I <sub>C</sub> = 50mA, V <sub>CE</sub> = 5.0V                                                                                                     |
| <b>SMALL SIGNAL CHARACTERISTICS</b>  |                      |                            |                               |      |                                                                                                                                                   |
| Output Capacitance                   | C <sub>obo</sub>     | 8.0 Typical                |                               | pF   | V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0                                                                                             |
| Input Capacitance                    | C <sub>ibo</sub>     | 15 Typical                 |                               | pF   | V <sub>EB</sub> = 0.5V, f = 1.0MHz, I <sub>C</sub> = 0                                                                                            |

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
  2. No purposefully added lead.
  3. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.
  5. Short duration pulse test used to minimize self-heating effect.

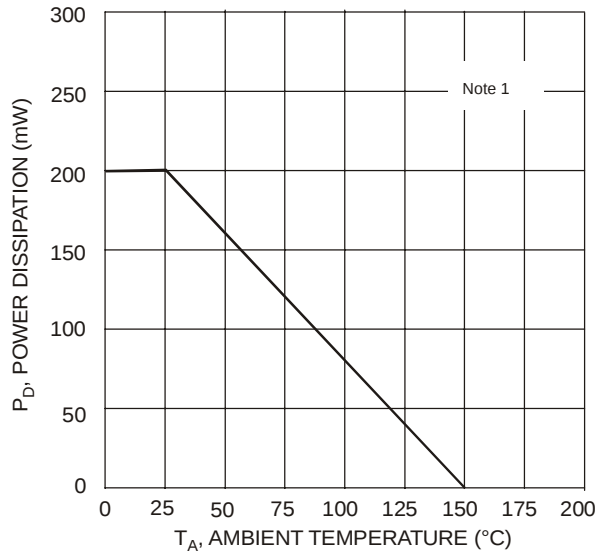


Fig. 1, Max Power Dissipation vs. Ambient Temperature

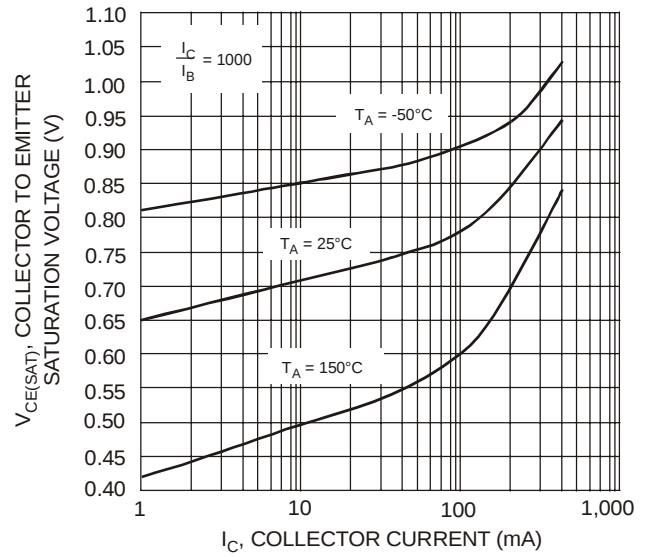


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

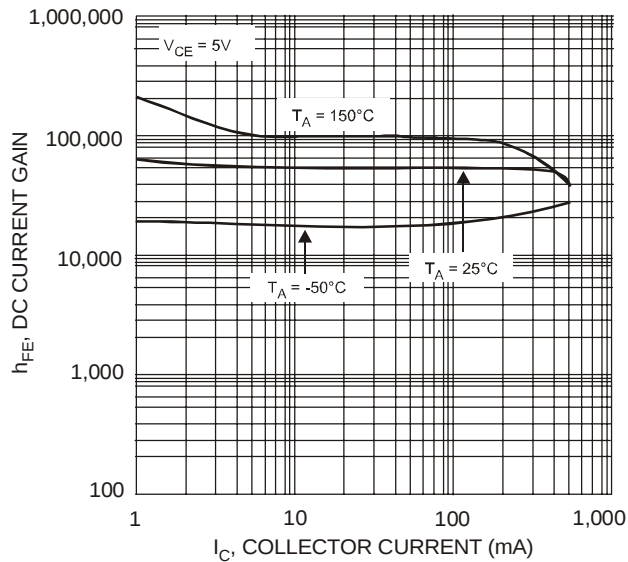


Fig. 3, DC Current Gain vs. Collector Current

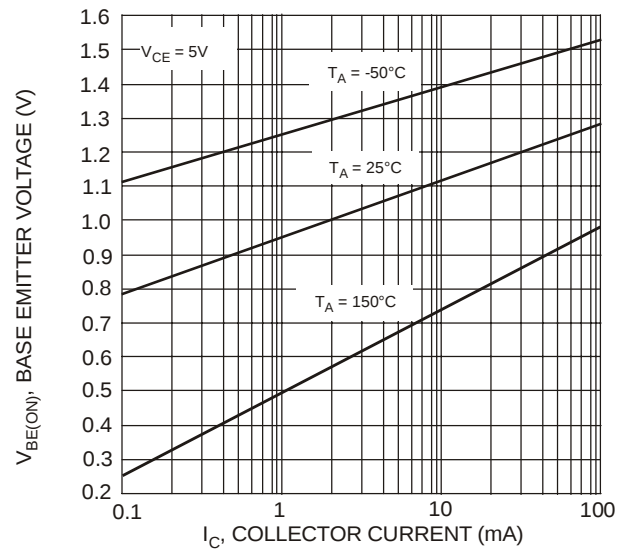


Fig. 4, Base Emitter Voltage vs. Collector Current

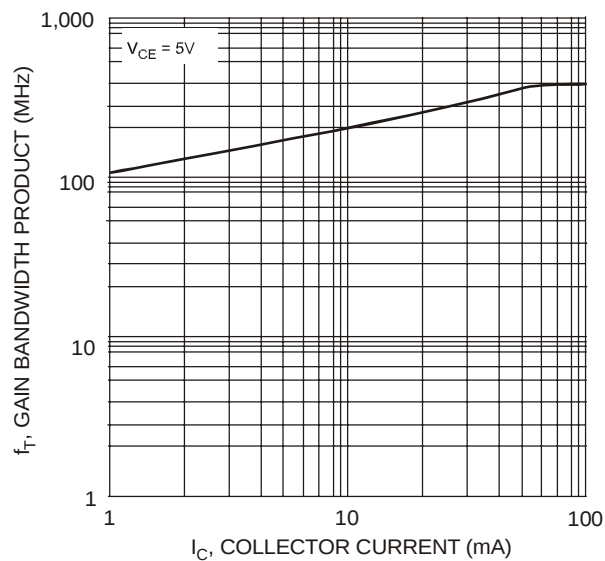


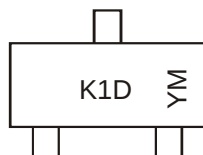
Fig. 5, Gain Bandwidth Product vs. Collector Current

## Ordering Information (Note 4 & 6)

| Device       | Packaging | Shipping         |
|--------------|-----------|------------------|
| MMST6427-7-F | SOT-323   | 3000/Tape & Reel |

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



K1D= Product Type Marking Code  
YM = Date Code Marking  
Y = Year ex: N = 2002  
M = Month ex: 9 = September

### Date Code Key

| Year | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | L    | M    | N    | P    | R    | S    | T    | U    | V    | W    | X    | Y    | Z    |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3   | 4   | 5   | 6   | 7   | 8   | 9   | O   | N   | D   |

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